

PATENT ASSIGNMENT COVER SHEET

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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT
CONVEYING PARTY DATA	
Name	Execution Date
HSIN-YI LEE	05/24/2016
CHENG-YEN TSAI	05/24/2016
DA-YUAN LEE	05/24/2016
RECEIVING PARTY DATA	
Name:	TAIWAN SEMICONDUCTOR MANUFACTURING CO., LTD.
Street Address:	NO. 8, LI-HSIN RD. 6
Internal Address:	SCIENCE-BASED INDUSTRIAL PARK
City:	HSIN-CHU
State/Country:	TAIWAN
Postal Code:	300-77
PROPERTY NUMBERS Total: 1	
Property Type	Number
Application Number:	15790739
CORRESPONDENCE DATA	
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ATTORNEY DOCKET NUMBER:	20151085 / 24061.3259US02
NAME OF SUBMITTER:	JANIE MARTINEZ-HOLM
SIGNATURE:	/JANIE MARTINEZ-HOLM/
DATE SIGNED:	10/24/2017
Total Attachments: 2	
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Docket No.: P20151085US00/24061.3259US01
Customer No.: 000042717

ASSIGNMENT

WHEREAS, we,

- | | | | |
|-----|----------------|----|--|
| (1) | Hsin-Yi Lee | of | Hsinchu City, Taiwan, Republic of China |
| (2) | Cheng-Yen Tsai | of | New Taipei City, Taiwan, Republic of China |
| (3) | Da-Yuan Lee | of | Hsinchu County, Taiwan, Republic of China |

have invented certain improvements in

ATOMIC LAYER DEPOSITION METHODS AND STRUCTURES THEREOF

for which we have executed an application for Letters Patent of the United States of America,

 X of even date filed herewith; and
 filed on and assigned application number ; and

WHEREAS, we authorize the attorney of record to update this document to include Patent Office information as deemed necessary (i.e., filing date, serial number, etc.);

WHEREAS, Taiwan Semiconductor Manufacturing Co., Ltd., ("TSMC"), No. 8, Li-Hsin Rd. 6, Science-Based Industrial Park Hsin-Chu, Taiwan 300-77, Republic of China is desirous of obtaining the entire right, title, and interest in, to and under the said invention and the said application in the United States of America and in any and all countries foreign thereto;

NOW, THEREFORE, for good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, and other good and valuable consideration, we have sold, assigned, transferred and set over, and by these presents do hereby sell, assign, transfer and set over, unto the said TSMC, its successors, legal representatives, and assigns, the entire right, title, and interest in, to and under the said invention, and the said application, and all divisional, renewal, substitutional, and continuing applications thereof, and all Letters Patent of the United States of America which may be granted thereon and all reissues and extensions thereof, and all applications for Letters Patent which may be filed for said invention in any country or countries foreign to the United States of America, and all extensions, renewals, and reissues thereof, and all prior patents and patent applications from which a filing priority of the above-described patent application may be obtained, including the right to collect past damages; and we hereby authorize and request the Commissioner of Patents of the United States of America, and any official of any country or countries foreign to the United States of America, whose duty it is to issue patents on applications as aforesaid, to issue all Letters Patent for said invention to the said TSMC, its successors, legal representatives and assigns, in accordance with the terms of this instrument.

AND WE HEREBY covenant that we have full right to convey the entire interest herein assigned, and that we have not executed, and will not execute, any agreement in conflict herewith.

AND WE HEREBY further covenant and agree that we will communicate to said TSMC, its successors, legal representatives and assigns, any facts known to us respecting said invention, and testify in any legal proceedings, sign all lawful papers, execute all divisional, renewal, substitutional, continuing, and reissue applications, make all rightful declarations and/or oaths

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and generally do everything possible to aid the said TSMC, its successors, legal representatives and assigns, to obtain and enforce proper patent protection for said invention in all countries.

Inventor Name: Hsin-Yi Lee

Residence Address: No. 66, Shije Road, East District
Hsinchu City, 30072, Taiwan, Republic of China

Dated: 24 / May / 2016

Hsin-Yi Lee
Inventor Signature

Inventor Name: Cheng-Yen Tsai

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Dated: 24 / May / 2016

Cheng-Yen Tsai
Inventor Signature

Inventor Name: Da-Yuan Lee

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Dated: 24 / May / 2016

Da-Yuan Lee
Inventor Signature